

IN THE CLAIMS

Please cancel Claims 5-10 without prejudice.

1. (Original) A method of manufacturing an active matrix pixel device comprising a thin film transistor (10) which includes a polycrystalline silicon channel (15) and doped source/drain regions (16,17), and a PIN diode (12) which includes a p-type doped region (26) and an n-type doped region (24) separated by an amorphous silicon intrinsic region (25), the method including the steps of:

(a) - forming a plurality of polycrystalline silicon islands on a substrate (14), one of which providing the transistor channel (15), and source/drain regions (16,17); and then,

(b) - depositing and patterning a layer of amorphous silicon to provide the intrinsic region (25) of the PIN diode (12) such that the intrinsic region overlies and contacts at least a part of one of the polycrystalline silicon islands which provides one of the p-type or n-type doped regions.

2. (Original) A method according to Claim 1, wherein the source/drain regions (16,17) and said one of the p-type or n-type doped regions (26,24) of the PIN diode are provided by the same polycrystalline silicon island.

3. (Original) A method according to claims 1 or 2, wherein the source/drain regions are doped n-type, and wherein the method further comprises the steps of:

(c) - depositing and patterning a layer of aluminium to define a top PIN diode contact (40) on the intrinsic region (25) of the PIN diode;

(d) - annealing the top PIN diode contact to cause aluminium ions to diffuse into the underlying intrinsic region to form the p-type doped region (26).

4. (Original) A method according to claim 3, further comprising the step of:

(e) - etching away part of the top PIN diode contact (40) so as to expose the PIN diode to input light (100).

5. (Cancelled)

6. (Cancelled)

7. (Cancelled)

8. (Cancelled)

9. (Cancelled)

10. (Cancelled)

11. (Original) An active matrix electroluminescent display device according to any preceding claim, wherein the PIN diode serves to measure the light intensity output (100) from an associated display element and supply a signal to drive circuitry connected thereto to enable modulation of the light output in accordance with the measured light intensity.